



### **40V Dual N-Channel Enhancement Mode MOSFET**

Voltage

40 V

Current

45 A

#### **Features**

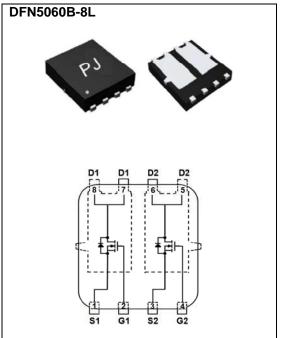
- R<sub>DS(ON)</sub>, V<sub>GS</sub>@10V, I<sub>D</sub>@15A<8mΩ
- $R_{DS(ON)}$ ,  $V_{GS}@4.5V$ ,  $I_{D}@8A<10.5m\Omega$
- High switching speed
- Improved dv/dt capability
- Low reverse transfer capacitance
- AEC-Q101 qualified
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

#### **Mechanical Data**

• Case: DFN5060B-8L Package

• Terminals : Solderable per MIL-STD-750, Method 2026

• Approx. Weight: 0.0035 ounces, 0.092 grams



## Maximum Ratings and Thermal Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		$V_{DS}$	40	\ /	
Gate-Source Voltage		$V_{GS}$	<u>+</u> 20	V	
Continuous Drain Current (Note 4)	T <sub>C</sub> =25°C	I <sub>D</sub>	45	А	
	T <sub>C</sub> =100°C		28		
Pulsed Drain Current (Note 1)	T <sub>C</sub> =25°C	I <sub>DM</sub>	180		
Power Dissipation	T <sub>C</sub> =25°C	Po	38.5	W	
	Tc=100°C		19.2		
Continuous Drain Current (Note 4)	T <sub>A</sub> =25°C	l <sub>D</sub>	10	А	
	T <sub>A</sub> =70°C		8		
Power Dissipation	T <sub>A</sub> =25°C	Po	2.0	W	
	T <sub>A</sub> =70°C		1.4		
Single Pulse Avalanche Energy (Note 6)		E <sub>AS</sub>	80	mJ	
Operating Junction and Storage Temperature Range		$T_{J}$ , $T_{STG}$	-55~175	°C	
Typical Thermal Resistance (Note 4,5)	Junction to Case	$R_{ heta JC}$	3.9	°C/W	
	Junction to Ambient	$R_{\theta JA}$	73.5		

• Limited only By Maximum Junction Temperature





### **Electrical Characteristics** (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V, I <sub>D</sub> =250uA	40	-	-	V
Gate Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =250uA	1	1.61	2.5	
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =15A	-	6.5	8	mΩ
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =4.5V, I <sub>D</sub> =8A	-	8	10.5	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =40V, V <sub>GS</sub> =0V	-	-	1	uA
Gate-Source Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> = <u>+</u> 20V, V <sub>DS</sub> =0V	-	-	<u>+</u> 100	nA
Dynamic (Note 7)						
Total Gate Charge	Qg	V <sub>DS</sub> =20V, I <sub>D</sub> =10A, V <sub>GS</sub> =4.5V (Note 1,2)	-	17	-	nC
Gate-Source Charge	Qgs		-	4.9	-	
Gate-Drain Charge	Qgd	VGS=4.5 V (***********************************	-	6.4	-	
Input Capacitance	Ciss	\/ QE\/ \/ Q\/	-	1759	-	pF
Output Capacitance	Coss	V <sub>DS</sub> =25V, V <sub>GS</sub> =0V, f=1MHZ	-	176	-	
Reverse Transfer Capacitance	Crss	I= IIVIMZ	-	126	-	
Turn-On Delay Time	td(on)	\/ 45\/   40	-	11	-	
Turn-On Rise Time	tr	V <sub>DD</sub> =15V, I <sub>D</sub> =1A,	-	21	-	ns
Turn-Off Delay Time	td(off)	$V_{GS}=10V, R_{G}=6\Omega$ (Note 1,2)	-	40	-	
Turn-Off Fall Time	tf	(······	-	25	-	
Drain-Source Diode						
Maximum Continuous Drain-Source	la la				45	Α
Diode Forward Current	I <sub>S</sub>		-	-	40	^
Diode Forward Voltage	V <sub>SD</sub>	I <sub>S</sub> =1A, V <sub>GS</sub> =0V	-	0.7	1	V

#### NOTES:

- 1. Pulse width<300us, Duty cycle<2%.
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Repetitive rating, pulse width limited by junction temperature  $T_{J(MAX)}$ =150°C. Ratings are based on low frequency and duty cycles to keep initial  $T_J$  =25°C.
- 4. The maximum current rating is package limited.
- 5. R<sub>OJA</sub> is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch<sup>2</sup> with 2oz.square pad of copper.
- 6. The test condition is L=0.1mH, I<sub>AS</sub>=40A, V<sub>DD</sub>=25V, V<sub>GS</sub>=10V, Starting T<sub>J</sub>=25°C.
- 7. Guaranteed by design, not subject to production testing.





#### **TYPICAL CHARACTERISTIC CURVES**

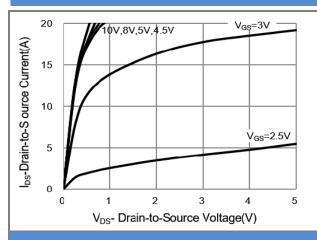
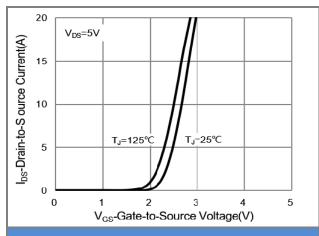


Fig.1 Output Characteristics



**Fig.2 Transfer Characteristics** 

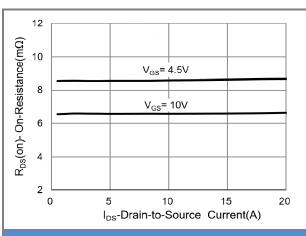


Fig.3 On-Resistance vs. Drain Current

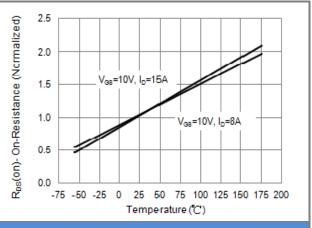
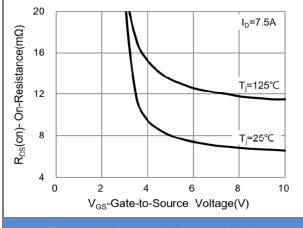


Fig.4 On-Resistance vs. Junction temperature





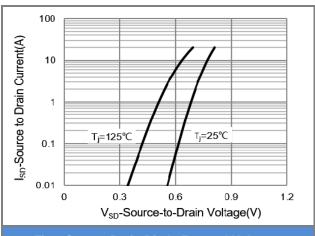


Fig.6 Source-Drain Diode Forward Voltage





#### **TYPICAL CHARACTERISTIC CURVES**

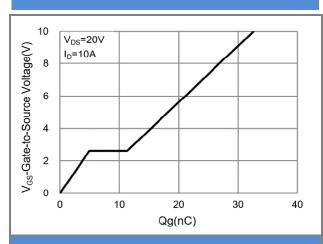


Fig.7 Gate-Charge Characteristics

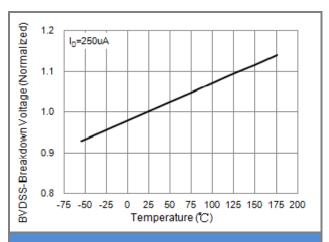


Fig.8 Breakdown Voltage Variation vs. Temperature

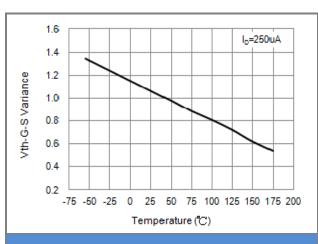


Fig.9 Threshold Voltage Variation with Temperature

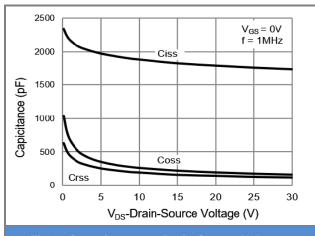


Fig.10 Capacitance vs. Drain-Source Voltage

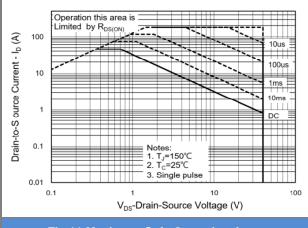
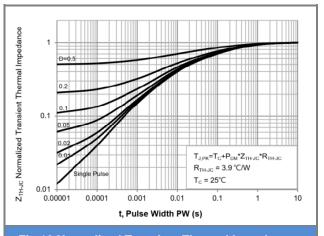


Fig.11 Maximum Safe Operating Area



**Fig.12 Normalized Transient Thermal Impedance** 

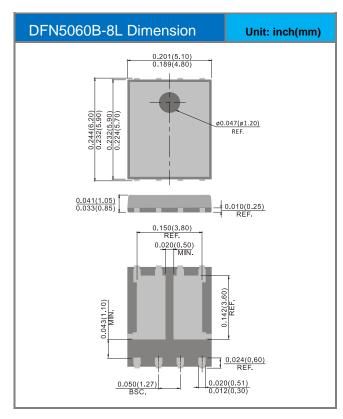


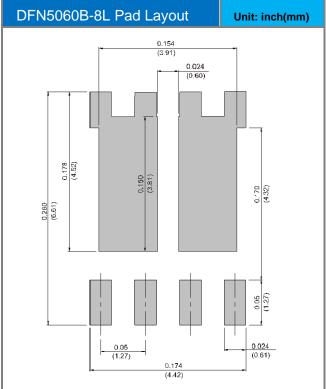


## Part No. Packing Code Version

Part No. Packing Code	Package Type	Packing Type	Marking	Version
PJQ5844-AU_R2_000A1	DFN5060B-8L	3000pcs / 13" reel	Q5844	Halogen free

## **Packaging Information & Mounting Pad Layout**









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